CMOS Digital Integrated Circuits Silicon Monolithic

74VHCT14AFT

1. Functional Description

· Hex Schmitt Inverter

2. General

The 74VHCT14AFT is an advanced high speed CMOS SCHMITT INVERTER fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Pin configuration and function are the same as the 74VHC04FT but the inputs have hysteresis and with its schmitt trigger function, the 74VHCT14AFT can be used as a line receivers which will receive slow input signals. The input voltage are compatible with TTL output voltage.

This device may be used as a level converter for interfacing 3.3 V to 5 V system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: $V_{CC} = 0 V$

3. Features

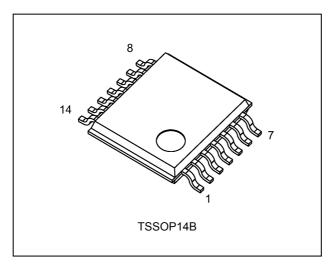
- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: $t_{pd} = 5.0 \text{ ns}$ (typ.) at $V_{CC} = 5.0 \text{ V}$
- (4) Low power dissipation: $I_{CC} = 2.0 \mu A \text{ (max)}$ at $T_a = 25 \text{ °C}$
- (5) Compatible with TTL inputs : $V_{IL} = 0.5 \text{ V (max)}$

$$: V_{IH} = 2.1 \text{ V (min)}$$

- (6) Power down protection is provided on all inputs and outputs.
- (7) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (8) Low noise: $V_{OLP} = 0.8 \text{ V (max)}$
- (9) Pin and function compatible with the 74 series (AC/HC/AHC/LV etc.) 14 type.

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

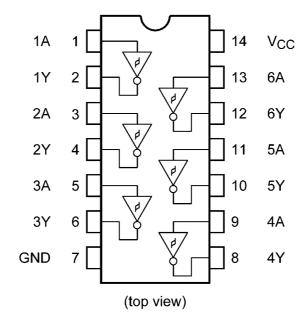
4. Packaging



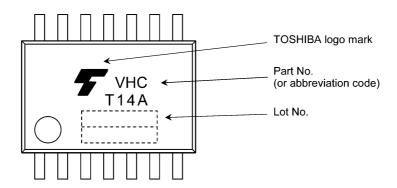
Start of commercial production



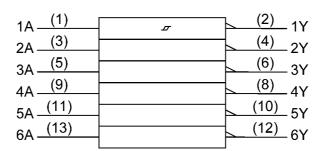
5. Pin Assignment



6. Marking



7. IEC Logic Symbol

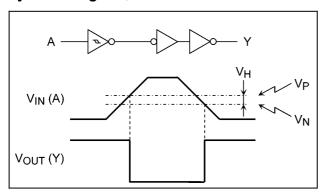




8. Truth Table

А	Y
L	Н
Н	L

9. System Diagram, Waveform



10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	V
Output voltage	V _{OUT}	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}		-20	mA
Output diode current	I _{OK}	(Note 3)	±20	mA
Output current	l _{out}		±25	mA
V _{CC} /ground current	I _{CC}		±50	mA
Power dissipation	P _D	(Note 4)	180	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: $V_{CC} = 0 V$

Note 2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.

Note 3: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

Note 4: 180 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.



11. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		4.5 to 5.5	V
Input voltage	V _{IN}		0 to 5.5	V
Output voltage	V _{OUT}	(Note 1)	0 to 5.5	٧
		(Note 2)	0 to V _{CC}	
Operating temperature	T _{opr}		-40 to 125	°C

Note: The operating ranges must be maintained to ensure the normal operation of the

device.

Unused inputs must be tied to either V_{CC} or GND.

Note 1: $V_{CC} = 0 V$

Note 2: High (H) or Low (L) state.

12. Electrical Characteristics

12.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
Positive threshold voltage	V _P	_		4.5	_	_	1.90	V
				5.5	_	_	2.10	
Negative threshold voltage	V _N	_		4.5	0.50	_	_	V
				5.5	0.60	_		
Hysteresis voltage	V _H	_		4.5	0.40	_	1.40	V
				5.5	0.40	_	1.50	
High-level output voltage	V _{OH}	$V_{IN} = V_{IL}$	I _{OH} = -50 μA	4.5	4.4	4.5		V
			I _{OH} = -8 mA	4.5	3.94	_	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA	4.5	_	0.0	0.1	V
			I_{OL} = 8 mA	4.5	_	_	0.36	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND	,	0 to 5.5	_	_	±0.1	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		5.5	_	_	2.0	μА
	I _{CCT}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_		1.35	mA
Output leakage current (Power-OFF)	I _{OPD}	V _{OUT} = 5.5 V		0	_	_	0.5	μА



12.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	_		4.5	_	1.90	V
				5.5		2.10	
Negative threshold voltage	V _N	_		4.5	0.50	_	V
				5.5	0.60	_	
Hysteresis voltage	V _H	_		4.5	0.40	1.40	V
				5.5	0.40	1.50	
High-level output voltage	V _{OH}	V _{IN} = V _{IL}	I_{OH} = -50 μ A	4.5	4.4	_	V
			I _{OH} = -8 mA	4.5	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA	4.5	_	0.1	V
			I_{OL} = 8 mA	4.5	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	20.0	μА
	I _{CCT}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I _{OPD}	V _{OUT} = 5.5 V		0	_	5.0	μА

12.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition	on	V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	_		4.5	_	1.90	V
				5.5	_	2.10	
Negative threshold voltage	V _N	_		4.5	0.50	_	V
				5.5	0.60	_	
Hysteresis voltage	V _H	_		4.5	0.40	1.40	V
				5.5	0.40	1.50	
High-level output voltage	V _{OH}	V _{IN} = V _{IL}	I _{OH} = -50 μA	4.5	4.4	_	V
			I_{OH} = -8 mA	4.5	3.70	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50 μA	4.5	_	0.1	V
			I_{OL} = 8 mA	4.5	_	0.55	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±2.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		5.5	_	40.0	μА
	I _{CCT}	Per input: V _{IN} = 3.4 V Other input: V _{CC} or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I _{OPD}	V _{OUT} = 5.5 V		0	_	20.0	μА



12.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		5.0 ± 0.5	15	_	5.0	7.6	ns
				50		6.5	9.6	
Input capacitance	C _{IN}		_		_	4	10	pF
Power dissipation capacitance	C _{PD}	(Note 1)	_		_	18	_	

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{|N} + I_{CC}/6 \text{ (per gate)}$

12.5. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_f = t_f = 3 ns)

Characteristics	Symbol	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	5.0 ± 0.5	15	1.0	9.0	ns
			50	1.0	11.0	
Input capacitance	C _{IN}	_		_	10	pF

12.6. AC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_r = t_f = 3 ns)

Characteristics	Symbol	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	5.0 ± 0.5	15	1.0	9.5	ns
			50	1.0	12.0	
Input capacitance	C _{IN}	_		_	10	pF

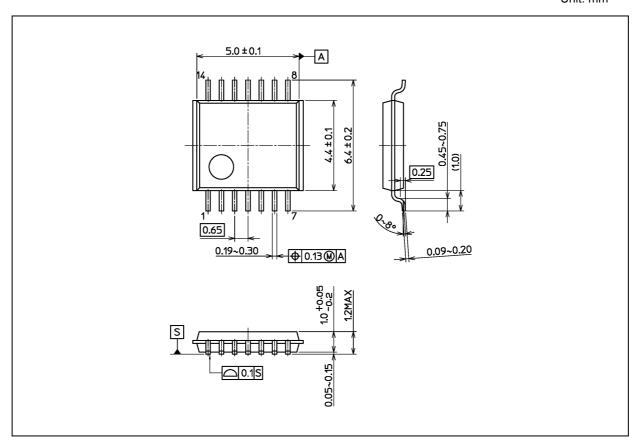
12.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OI}	V _{OLP}	C ₁ = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.5	-0.8	V
Minimum high-level dynamic input voltage	V_{IHD}	C _L = 50 pF	5.0	_	2.1	٧
Maximum low-level dynamic input voltage	V_{ILD}	C _L = 50 pF	5.0	_	0.5	V



Package Dimensions

Unit: mm



Weight: 0.054 g (typ.)

	Package Name(s)
Nickname: TSSOP14B	



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